

MBRF1090CT, MBRF10100CT

Vishay General Semiconductor

COMPLIANT

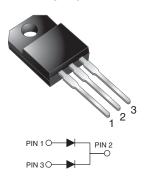
HALOGEN

FREE

Dual High Voltage Trench MOS Barrier Schottky Rectifier

TMBS®

ITO-220AB



| PRIMARY CHARACTERISTICS | | | | | |
|-------------------------|----------------|--|--|--|--|
| I _{F(AV)} | 2 x 5.0 A | | | | |
| V_{RRM} | 90 V, 100 V | | | | |
| I _{FSM} | 120 A | | | | |
| V _F | 0.75 V | | | | |
| T _J max. | 150 °C | | | | |
| Package | ITO-220AB | | | | |
| Diode variations | Common cathode | | | | |

FEATURES

- Trench MOS Schottky technology
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters or polarity protection application.

MECHANICAL DATA

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

| MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted) | | | | | | |
|--|--------------|-----------------------------------|---------------|-------------|------|--|
| PARAMETER | | SYMBOL | MBRF1090CT | MBRF10100CT | UNIT | |
| Max. repetitive peak reverse voltage | | V_{RRM} | 90 | 100 | V | |
| Working peak reverse voltage | | V_{RWM} | 90 | 100 | V | |
| Max. DC blocking voltage | | V_{DC} | 90 | 100 | V | |
| Max. average forward rectified current at T _C = 105 °C | total device | 1 | 10 | | А | |
| | per diode | I _{F(AV)} | | .0 | | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | | I _{FSM} | 120 | | А | |
| Non-repetitive avalanche energy at $T_J = 25$ °C, L = 60 mH per diode | | E _{AS} | 60 | | mJ | |
| Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C per diode | | I _{RRM} | 0.5 | | А | |
| Voltage rate of change (rated V _R) | | dV/dt | 10 000 | | V/µs | |
| Operating junction and storage temperature range | | T _J , T _{STG} | - 65 to + 150 | | °C | |
| Isolation voltage from terminal to heatsink with t = 1 min | | V_{AC} | 1500 | | V | |

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| ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted) | | | | | | |
|---|------------------------|-------------------------|---------------------|------------|-------------|------|
| PARAMETER | TEST CONDITIONS | | SYMBOL | MBRF1090CT | MBRF10100CT | UNIT |
| Maximum instantaneous forward voltage per diode (1) | $I_F = 5.0 \text{ A}$ | T _C = 125 °C | V _F 0.75 | | 75 | V |
| | I _F = 5.0 A | T _C = 25 °C | ٧F | 0.85 | | |
| Maximum reverse current per diode at | | T _J = 25 °C | I_ | 10 | 00 | μΑ |
| working peak reverse voltage (2) | | T _J = 100 °C | I _R | 6 | .0 | mA |

Notes

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

| THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted) | | | | | |
|---|----------------|------------------------|--|------|--|
| PARAMETER | SYMBOL | MBRF1090CT MBRF10100CT | | UNIT | |
| Typical thermal resistance per diode | $R_{	heta JC}$ | 6.8 | | °C/W | |

| ORDERING INFORMATION (EXAMPLE) | | | | | | | |
|--------------------------------|-------------------|-----------------|--------------|---------------|---------------|--|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | |
| ITO-220AB | MBRF10100CT-M3/4W | 1.75 | 4W | 50/tube | Tube | | |

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

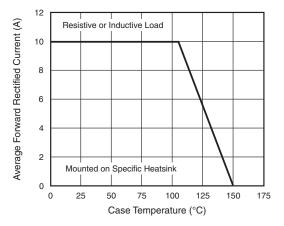


Fig. 1 - Forward Current Derating Curve

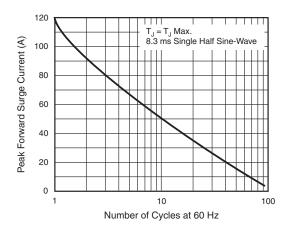


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode





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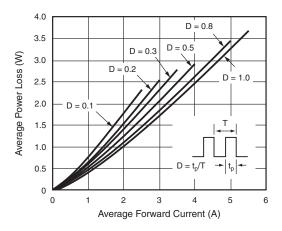


Fig. 3 - Forward Power Loss Characteristics Per Diode

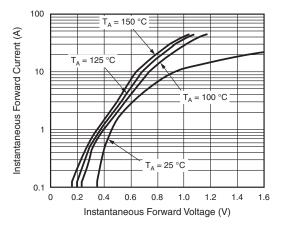


Fig. 4 - Typical Instantaneous Forward Characteristics Per Diode

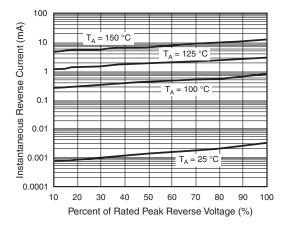


Fig. 5 - Typical Reverse Characteristics Per Diode

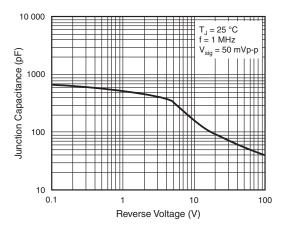


Fig. 6 - Typical Junction Capacitance Per Diode

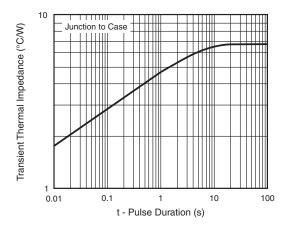


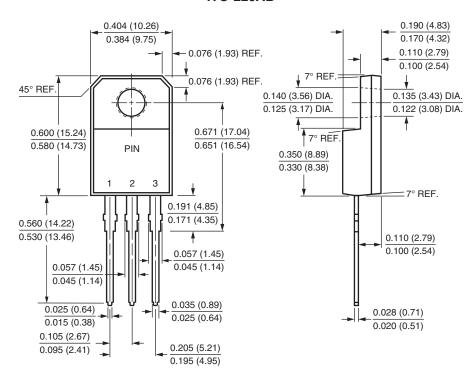
Fig. 7 - Typical Transient Thermal Impedance Per Diode



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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

ITO-220AB





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AMEYA360 Components Supply Platform

Authorized Distribution Brand:

























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